

# Silicon Diode

## **RGP30M**

1000V / 3A

# DATASHEET

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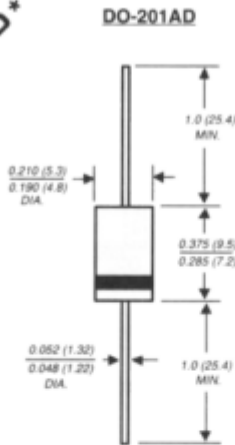
OEM – General Semiconductor

Source: General Semiconductor Databook 1998

# RGP30A THRU RGP30M

**GLASS PASSIVATED JUNCTION FAST SWITCHING RECTIFIER**  
 Reverse Voltage - 50 to 1000 Volts      Forward Current - 3.0 Amperes

**PATENTED\***



Dimensions in inches and (millimeters)  
 \* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306



## FEATURES

- ♦ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ♦ Glass passivated cavity-free junction
- ♦ Capable of meeting environmental standards of MIL-S-19500
- ♦ High temperature metallurgically bonded construction
- ♦ 3.0 Ampere operation at  $T_A=55^{\circ}\text{C}$  with no thermal runaway
- ♦ Typical  $I_R$  less than  $0.2\mu\text{A}$
- ♦ Fast switching for high efficiency
- ♦ High temperature soldering guaranteed  $350^{\circ}\text{C}/10$  seconds,  $0.375"$  (9.5mm) lead length, 5 lbs. (2.3kg) tension

## MECHANICAL DATA

**Case:** JEDEC DO-201AD molded plastic over glass body  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.04 ounce, 1.12 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at  $25^{\circ}\text{C}$  ambient temperature unless otherwise specified.

	SYMBOLS	RGP 30A	RGP 30B	RGP 30D	RGP 30G	RGP 30J	RGP 30K	RGP 30M	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=55^{\circ}\text{C}$	$I_{(AV)}$	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	125.0							Amps
Maximum instantaneous forward voltage at 3.0A	$V_F$	1.3							Volts
Maximum DC reverse current at rated DC blocking voltage $T_A=25^{\circ}\text{C}$ $T_A=125^{\circ}\text{C}$	$I_R$	5.0 100.0							$\mu\text{A}$
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at $T_A=55^{\circ}\text{C}$	$I_{R(AV)}$	100.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	150			250	500			ns
Typical junction capacitance (NOTE 2)	$C_J$	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	20.0							$^{\circ}\text{C}/\text{W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +175							$^{\circ}\text{C}$

**NOTES:**

- (1) Reverse recovery test conditions:  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $t_{rr}=0.25\text{A}$
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

**RATINGS AND CHARACTERISTIC CURVES RGP30A THRU RGP30M**

